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Comparative Estimation of Electrical Characteristics of a Photovoltaic Module Using Regression and Artificial Neural Network Models

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Abstract: Accurate modeling of photovoltaic (PV) modules under outdoor conditions is essential to facilitate the optimal design and assessment of PV systems. As an alternative model to the translation equations based on regression methods, various data-driven models have been adopted to estimate the current–voltage (I–V) characteristics of a photovoltaic module under varying operation conditions. In this paper, artificial neural network (ANN) models are compared with the regression models for five parameters of a single diode solar cell. In the configuration of the proposed PV models, the five parameters are predicted by regression and neural network models, and these parameters are put into an explicit expression such as the Lambert W function. The multivariate regression parameters are determined by using the least square method (LSM). The ANN model is constructed by using a four-layer, feed-forward neural network, in which the inputs are temperature and solar irradiance, and the outputs are the five parameters. By training an experimental dataset, the ANN model is built and utilized to predict the five parameters by reading the temperature and solar irradiance. The performance of the regression and ANN models is evaluated by using root mean squared error (RMSE) and mean absolute percentage error (MAPE). A comparative study of the regression models.

Keywords: regression; artificial neural network; I–V characteristics; photovoltaic module



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1. Introduction

The output power of photovoltaic (PV) systems is strongly affected under arbitrary operating conditions such as temperature and solar irradiance of PV modules [1,2]. However, highly predictive and efficient models across different temperatures and irradiances have not been established [3–6]. In addition, their nonlinear characteristics make highly predictive modeling even more difficult [7–13]. The single-diode model (SDM) with five parameters is widely utilized to reproduce the current-voltage (I-V) characteristics [5-8]. Owing to the inherent implicit expression for the electrical equivalent circuit of the SDM, analytical and explicit I–V models have been proposed to calculate the I–V relationship [1,14–16]. The explicit I–V model based on the Lambert W function is simple and efficient, while the implicit model requires more computational time [14–16]. Although optimization methods have been proposed to obtain the five parameters at the standard test condition (STC), significant extraction efforts are required to consider the dependence of unknown parameters on temperature and solar irradiance [3–8,17–21]. For arbitrary operating conditions, the performance of the parameter translation model is greatly limited by the chosen translation equation and correction factors [13,17–21]. In order to construct a complete PV model for climatic conditions, the translational formula should be further modified [17,19] and new parameters may need to be taken into account [18,20,21]. Moreover, the accuracy of the translational formula varies significantly at low irradiance levels [3-5]. However, artificial neural network (ANN) models provide parameter identification, I-V prediction with higher accuracy directly from the measured data [22,23], and fault detection and diagnosis for

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photovoltaic systems [24–26]. To accurately estimate the performance of PV modules under varying operating conditions, it is necessary to establish a data-driven model for the five parameters with change in irradiance and temperature [27–37]. In recent years, improved ANN models have been proposed by adding more variables [38] and utilizing the efficient training schemes and processing of neural networks [39-42]. This paper compares the performance of regression and ANN models for the five parameters in predicting the I-V relationship of a PV module based on an explicit expression. The results show that the ANN model provides better performance than the regression model. The novelty of the proposed approach lies primarily in the successful integration of comparative models into an analytical and explicit Lambert W function, in contrast with the previous practice for the electrical equivalent circuits. (1) In this new framework, temperature and solar irradiance serve as inputs to establish the regression and ANN models for I–V prediction under arbitrary operating conditions. (2) An advanced ANN model for the five parameters is developed by determining an optimum ANN architecture to improve the estimation of the model. The ANN model developed can provide an efficient method with higher accuracy in predicting I–V characteristics, compared to the regression model.

In this work, the modeling process begins in Section 2 with the theoretical formulation of an explicit I–V model and translation equations for the five parameters. Section 3 describes the regression and ANN models, followed in Section 4 by a comparative validation of both the models against the experimental data for a PV module. In Section 5, the main conclusions are drawn.

2. Theoretical Models

2.1. Explicit and Analytical I-V Model

The PV-equivalent circuit of a single diode with two resistors is shown in Figure 1. The I–V relationship of a PV module can be expressed with a single diode as [1,2,5–8]:

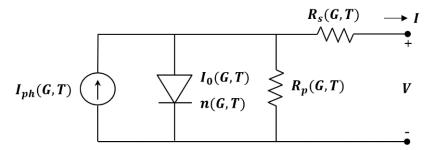


Figure 1. PV-equivalent circuit of a single diode with series and parallel resistance at arbitrary irradiance (G) and temperature (T).

$$I = I_{ph} - I_0 \left[\exp\left(\frac{V + IR_s}{nV_t}\right) - 1 \right] - \frac{V + IR_s}{R_p}$$
(1)

where I_{ph} is the photogenerated current, I_0 is the diode reverse saturation current, n is the ideality factor, and R_s and R_p is the series and parallel resistance, respectively. The thermal voltage is given by $V_t = N_s k_b T/q$, where N_s is the number of series-connected cells, k_b is the Boltzmann constant, and T is the temperature. The explicit solution of the PV module transcendent Equation (1) is given as a function of the Lambert W function [1,14–16]:

$$I = \frac{R_p \left(I_{ph} + I_0 \right) - V}{R_s + R_p} - \frac{nV_t}{R_s} W(\alpha(V))$$
 (2)

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$$\alpha(V) = \frac{R_s R_p I_0}{n V_t (R_s + R_p)} e^{\frac{R_p (R_s I_{ph} + R_s I_0 + V)}{n V_t (R_s + R_p)}}$$
(3)

2.2. Five Parameters as a Function of Temperature and Solar Irradiance

Environmental conditions such as temperature (T) and solar irradiance (G) have strong effects on the I–V characteristics of the PV module. In order to extract accurate estimates of the model parameters under arbitrary T and G, mathematical expressions for the five parameters are reformulated by using the advantage of the previous formula [1,2,5–8]. The I–V curve translation for desired solar irradiance and temperature (G, T) from STC (G_0 , T_0) is obtained by using the short circuit current (I_{sc}) and the open circuit voltage (V_{oc}). Assuming the condition $I_{sc} \approx I_{ph}$, $I_{sc}(G,T)$ and $V_{oc}(G,T)$ are determined as [1,2,5–8]:

$$I_{sc}(G,T) \approx I_{ph}(G,T) = \left(\frac{G}{G_0}\right) \left[I_{ph0} + \alpha_i(T - T_0)\right]$$
 (4)

$$V_{oc}(G,T) = V_{oc0} \left[1 + \alpha_v (T - T_0) + \beta_v V_t \ln \left(\frac{G}{G_0} \right) \right]$$
 (5)

where I_{ph0} and V_{oc0} are the photogenerated current and open circuit voltage at standard test conditions, respectively; α_i and α_v are temperature coefficients and β_v is an irradiance coefficient. From the relationship $n = n_0(V_{oc}/V_{oc0})$ and $R_{s,p} = R_{s0,p0}(V_{oc}/V_{oc0})(I_{sc0}/I_{sc})$, the values of the translated parameters n(G,T), $R_s(G,T)$, and $R_p(G,T)$ are calculated as follows [1,2,7]:

$$n(G,T) = n_0 \left[1 + \alpha_n (T - T_0) + \beta_n V_t \ln \left(\frac{G}{G_0} \right) \right]$$
 (6)

$$R_{s}(G,T) = R_{s0} \frac{1 + \alpha_{R_{s}}(T - T_{0}) + \beta_{R_{s}} V_{t} \ln\left(\frac{G}{G_{0}}\right)}{\left(\frac{G}{G_{0}}\right) \left[1 + \alpha_{R_{s}}^{*}(T - T_{0})\right]}$$
(7)

$$R_{p}(G,T) = R_{p0} \frac{1 + \alpha_{R_{p}}(T - T_{0}) + \beta_{R_{p}}V_{t}\ln\left(\frac{G}{G_{0}}\right)}{\left(\frac{G}{G_{0}}\right)\left[1 + \alpha_{R_{p}}^{*}(T - T_{0})\right]}$$
(8)

where n_0 , R_{s0} , and R_{p0} are the ideality factor, series resistance, and parallel resistance at standard test conditions, respectively; α_n , α_{R_s} , $\alpha_{R_p}^*$, α_{R_p} , and $\alpha_{R_p}^*$ are temperature coefficients and β_n , β_{R_s} , and β_{R_p} are irradiance coefficients. By setting I=0 in (1), the translation expression for the reverse saturation current $I_0(G,T)$ as a function of $I_{ph}(G,T)$, $V_{oc}(G,T)$, n(G,T), and $R_{s,p}(G,T)$ is obtained as [1,2,7]:

$$I_0(G,T) = \frac{I_{ph}(G,T) - \frac{V_{oc}(G,T)}{R_p(G,T)}}{\exp\left(\frac{V_{oc}(G,T)}{n(G,T) V_t}\right) - 1}$$
(9)

3. Parameter Identification Approaches

3.1. Multiple Regression

The multivariate regression analysis is employed to model the statistical relationship between inputs (G, T) and outputs $(I_{ph}, n, R_s, R_p, I_0)$. The parametric regression equation for a linear or nonlinear function f is expressed as [43–45]:

$$y = f(X_1, \dots, X_n; \theta_1, \dots, \theta_m) + \varepsilon \tag{10}$$

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where y is an $n \times 1$ vector of dependent variable, X_1, \ldots, X_n are an $n \times m$ matrix of independent variables, $\theta_1, \ldots, \theta_m$ are an $m \times 1$ vector of regression parameters, and ε is an $n \times 1$ vector of random error. The regression parameters $\theta_1, \ldots, \theta_m$ are usually determined using the least square method (LSM) to minimize $\sum_{i=1}^k (y_i - f(X_{1i}, \ldots, X_{ni}; \theta_1, \ldots, \theta_m))^2$ with different sample points k. Based on the estimated regression parameters, the optimum regression model is chosen for prediction.

3.2. Artificial Neural Network (ANN)

The artificial neural network is specified in modeling complex systems, especially nonlinear or random variable systems. The multilayer perceptron (MLP), known as the fully connected feed-forward network for supervised learning, is the most common and successful for modeling nonlinear systems [22,23,31]. The MLP network configuration has an input layer, two hidden layers, and an output layer. The input layer consists of two neurons (G, T), and the output layer contains five neurons (I_{ph} , n, R_s , R_p , I_0). Every neuron in one layer is fully connected to every neuron in the next layer. By using the activation function of a hyperbolic tangent sigmoid function for N neurons, the output $h_i^{(k)}$ of the ith neuron in the kth hidden layer is computed as follows [22,23]:

$$h_i^{(1)} = \tanh\left(\sum_{j=1}^2 w_{ij}^{(1)} x_j + b_i^{(1)}\right) \tag{11}$$

$$h_i^{(2)} = \tanh\left(\sum_{j=1}^N w_{ij}^{(2)} h_j^{(1)} + b_i^{(2)}\right)$$
 (12)

where x_j is the jth input to the neuron, $w_{ij}^{(k)}$ is the weight for the ith neuron and jth input in the jth hidden layer, and jth is the bias for the jth neuron in the jth hidden layer. With the use of a linear activation function for neurons in the output layer, the network's output can be written as

$$y_i = \sum_{j=1}^{N} w_{ij}^{(3)} h_j^{(2)} + b_i^{(3)}$$
 (13)

In the vectorized form with a weight matrix $W^{(k)}$, an activation vector $h^{(k)}$, and a bias vector $b^{(k)}$, the network's computations are given by [22,23]:

$$h^{(1)} = \tanh\left(W^{(1)}x + b^{(1)}\right) \tag{14}$$

$$h^{(2)} = \tanh\left(W^{(2)}h^{(1)} + b^{(2)}\right)$$
 (15)

$$y = W^{(3)}h^{(2)} + b^{(3)} \tag{16}$$

where $x = [G\ T]^T$ is the transpose of the input vector x. The neural network is trained by using the Levenberg–Marquardt algorithm, a method used extensively for learning a feed-forward network, to realize the rapid correction of network weights and biases. Since the initial value of weight and bias affects the training results, the neural network can be retrained several times to obtain a neural network with excellent universality. The configuration of the proposed model is summarized in Figure 2. The five parameters are predicted by a MLP neural network, and these parameters are put into the Lambert W function.

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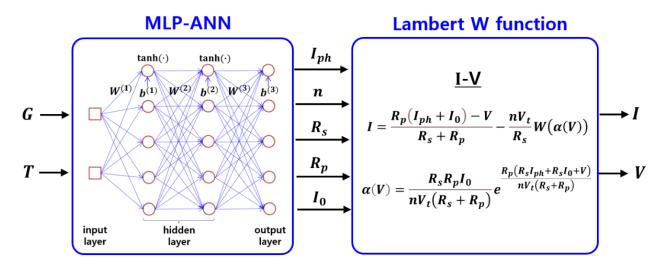


Figure 2. Configuration of the proposed photovoltaic model.

4. Model Verification

The validation of the regression and ANN models for the five parameters (I_{ph} ,n, R_s , R_p , I_0) is assessed by using the experimental data of the monocrystalline SM55 PV panel ($N_s = 36$) [1]. The five parameters are extracted by using the quality factor variation method from the manufacturer's data sheet [1,17]. After determining the parameters at standard test conditions ($G_0 = 1000 \text{ W/m}^2$, $T_0 = 298 \text{ K}$), the procedure is applied to estimate variations in the five parameters for different temperature levels ($T = 298 \sim 343 \text{ K}$) and solar irradiance levels ($G = 200 \sim 1000 \text{ W/m}^2$). The database obtained from the procedure is used to develop the multiple regression models for $I_{ph}(G,T)$, n(G,T), $R_s(G,T)$, $R_s(G,T)$, and $I_0(G,T)$.

Table 1 shows the regression models and coefficient of determination R^2 estimated by using Equations (4)–(9). As shown in Table 1, the regression models have a high coefficient of determination ($R^2 = 0.9692 \sim 1.000$), and $I_0(G, T)$ is obtained by other parameters with a high coefficient of determination.

Table 1.	Regression	model and	R^2 for	parameters	estimated	from ex	perimental data.

Parameters	Regression Models and \mathbb{R}^2				
$I_{ph}(G,T)$ (A)	$\left(\frac{G}{G_0}\right)\left[3.457+1.407\times 10^{-3}(T-T_0) ight]$, $R^2=1.000$				
$V_{oc}(G,T)$ (V)	$\left(\frac{G}{G_0}\right) \left[3.457 + 1.407 \times 10^{-3} (T - T_0)\right], R^2 = 1.000$ $21.63 \left[1 - 3.434 \times 10^{-3} (T - T_0) + 1.752 \times 10^{-4} V_t \ln\left(\frac{G}{G_0}\right)\right],$ $R^2 = 0.9985$				
n(G,T)	$1.084 \left[1 - 8.455 \times 10^{-4} (T - T_0) + 2.749 \times 10^{-4} V_t \ln \left(\frac{G}{G_0} \right) \right],$ $R^2 = 0.9692$				
$R_s(G,T)(\Omega)$	$0.4724 \frac{1 + 1.405 \times 10^{-2} + 6.854 \times 10^{-4} V_t \ln\left(\frac{G}{G_0}\right)}{\left(\frac{G}{G_0}\right) \left[1 + 3.488 \times 10^{-2} (T - T_0)\right]} , R^2 = 0.9938$				
$R_p(G,T)\left(\Omega\right)$	$222rac{1+1.890 imes10^{-2}+7.246 imes10^{-4}V_{t}\ln\left(rac{c}{c_{0}} ight)}{\left(rac{c}{c_{0}} ight)[1+2.515 imes10^{-2}(T-T_{0})]}$, $R^{2}=0.9926$				
$I_0(G,T)$ (A)	$\left[I_{ph}(G,T) - \frac{V_{oc}(G,T)}{R_p(G,T)}\right] / \left[\exp\left(\frac{V_{oc}(G,T)}{n(G,T)V_t}\right) - 1\right]$				

The best ANN model has an input layer with two variables, two hidden layers with five neurons in each layer, and an output layer with five variables (2-5-5-5 topology). Logarithm data preprocessing is used to improve the ANN model accuracy for the reverse saturation current $I_0(G, T)$. For training the ANN model, the offline method is utilized to generate the dataset for the five parameters of the PV panel, which is extracted from manufacturer's data sheet. Figure 3 shows the dependence of five parameters on temperature and solar

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irradiance for the regression model and ANN model. The correlation coefficients are employed to evaluate the accuracy of the ANN model for the five parameters, including the training, validation, and testing phases. As a result, the correlation coefficients with values greater than 99.85% were observed between the predicted and measured data in all network phases.

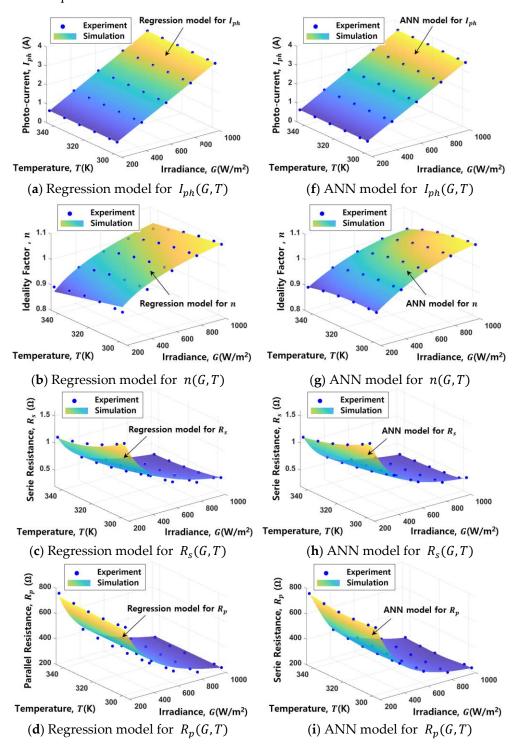


Figure 3. Cont.

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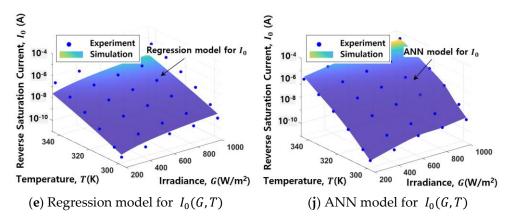


Figure 3. Dependence of the five parameters on temperature and solar irradiance for the regression model (**a**–**e**) and ANN model (**f**–**j**).

As plotted in Figure 4, two different statistical metrics based on the measured and estimated five parameters are employed to compare the accuracy of the ANN model with the regression model, including root mean squared error (RMSE) and mean absolute percentage error (MAPE), as follows [14,15]:

$$RMSE = \sqrt{\frac{1}{n} \sum_{i=1}^{n} (y_{m,i} - y_{e,i})^2}$$
 (17)

$$MAPE = \frac{1}{n} \sum_{i=1}^{n} \left| \frac{y_{m,i} - y_{e,i}}{y_{m,i}} \right| \times 100 \,(\%)$$
 (18)

where $y_{m,i}$ and $y_{e,i}$ are the measured and estimated values, respectively. Both RMSE and MAPE values of the ANN models are lower than those of the regression models. This is attributed to the strong capability of MLP–ANN models to learn the nonlinear relationship between the inputs and the outputs, whereas the regression models may be limited to a specific condition. Figure 5a,b show I–V characteristics and the absolute error by simulated and experimental data at different irradiances and temperatures, respectively. It is found that the absolute error values of the ANN models are lower than the regression models, resulting from the better performance of the ANN models for the five parameters shown in Figure 3. Table 2 shows the comparison of maximum absolute errors of the I–V curves estimated from the proposed ANN model and different models for the SM55 PV panel. As can be seen, the maximum absolute errors of the proposed ANN model are much lower than the other models for different irradiances and temperatures. These results justify the higher accuracy of the ANN models, compared with other works [1,4,46].

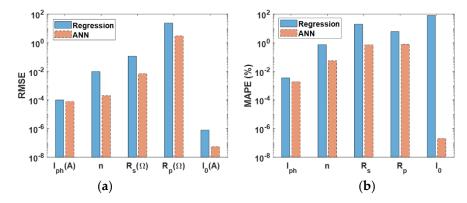


Figure 4. Statistical metrics for the five parameters in evaluating the accuracy of the regression model and ANN model: (a) RMSE and (b) MAPE.

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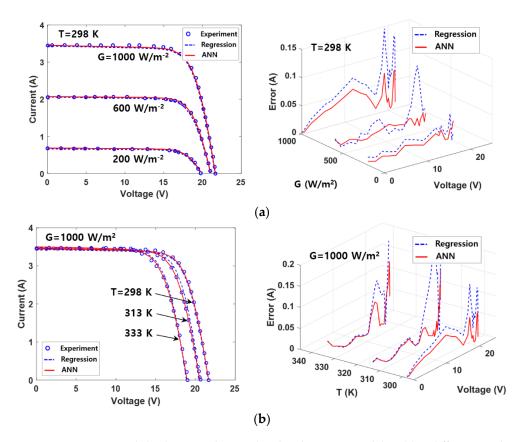


Figure 5. I–V curves and absolute error by simulated and experimental data (**a**) at different irradiances and (**b**) at different temperatures.

Table 2. Comparison of maximum absolute errors estimated from different models.

Temperature	Irradiance	Maximum Absolute Errors (A) of I–V Curves for SM55 Panel					
T (K)	G (W/m ²)	Proposed ANN Model	Model 1 [1]	Model 2 [4]	Model 3 [46]		
	200	0.02	0.03	0.03	0.08		
298	600	0.01	0.04	0.06	0.05		
	1000	0.06	0.08	0.06	0.06		
298		0.04	0.07	0.06 (293 K)	0.10 (293 K)		
313	1000	0.09	0.16	0.15	0.09		
333		0.09	0.12	0.10	0.20		

5. Conclusions

The electrical characteristics of a PV module under arbitrary operating conditions have been estimated by using the regression and ANN models. The models are utilized to predict the five parameters of a single diode solar cell, and the parameters are combined with an explicit equation for I–V characteristics. The inputs of the regression and ANN models are temperature and solar irradiance, while the outputs are the five parameters. The dataset needed for the five parameters was extracted from manufacturer's data sheet and used to construct the regression and ANN models. The best neural network architecture had a 2-5-5-5 topology for the five parameters, leading to correlation coefficients with values greater than 99.85%. Both the RMSE and MAPE values of the ANN models were found to be lower than those of the regression models. With comparative results, the ANN models show better performance than the regression models in predicting I–V characteristics under varying temperature and solar irradiance. It is applicable to extend the higher capability

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of ANN models to the prediction of electrical characteristics for diverse solar cells under actual weather conditions.

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